



## Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on  $V_F$

## Benefits

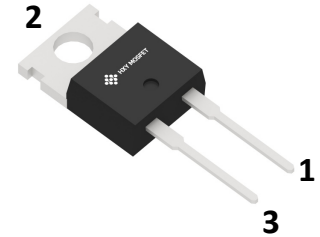
- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

## Applications

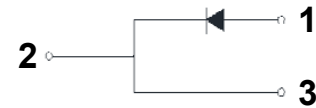
- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



| Part Number    | Package    | Qty(PCS) |
|----------------|------------|----------|
| FFSP2065B-F085 | TO-220C-2L | 50       |



TO-220C-2L



## Maximum Ratings ( $T_C = 25^\circ\text{C}$ unless otherwise specified)

| Symbol         | Parameter                                  | Value          | Unit             | Test Conditions                                                                                                       |
|----------------|--------------------------------------------|----------------|------------------|-----------------------------------------------------------------------------------------------------------------------|
| $V_{RRM}$      | Repetitive Peak Reverse Voltage            | 650            | V                |                                                                                                                       |
| $V_{RSM}$      | Surge Peak Reverse Voltage                 | 650            | V                |                                                                                                                       |
| $V_{DC}$       | DC Blocking Voltage                        | 650            | V                |                                                                                                                       |
| $I_F$          | Continuous Forward Current                 | 20             | A                | $T_C = 125^\circ\text{C}$                                                                                             |
| $I_{FRM}$      | Repetitive Peak Forward Surge Current      | 81             | A                | $T_C = 110^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave                                                             |
| $I_{FSM}$      | Non-Repetitive Peak Forward Surge Current  | 123<br>104     | A                | $T_C = 25^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave<br>$T_C = 150^\circ\text{C}$ , $t_p = 10$ ms, Half Sine Wave |
| $I_{F,Max}$    | Non-Repetitive Peak Forward Surge Current  | 450            | A                | $T_C = 25^\circ\text{C}$ , $t_p = 10$ $\mu\text{s}$ , Pulse                                                           |
| $P_{tot}$      | Power Dissipation                          | 115            | W                | $T_C = 25^\circ\text{C}$                                                                                              |
| $T_J, T_{stg}$ | Operating Junction and Storage Temperature | -55 to<br>+175 | $^\circ\text{C}$ |                                                                                                                       |



Electrical Characteristics

| Symbol           | Parameter                       | Typ.        | Max.     | Unit          | Test Conditions                                                                                                                            |
|------------------|---------------------------------|-------------|----------|---------------|--------------------------------------------------------------------------------------------------------------------------------------------|
| $V_F$            | Forward Voltage                 | 1.35<br>1.5 | 1.5<br>- | V             | $I_F = 20\text{ A}$ , $T_J = 25^\circ\text{C}$<br>$I_F = 20\text{ A}$ , $T_J = 175^\circ\text{C}$                                          |
| $I_R$            | Reverse Current                 | 0.06<br>12  | 100<br>- | $\mu\text{A}$ | $V_R = 650\text{ V}$ , $T_J = 25^\circ\text{C}$<br>$V_R = 650\text{ V}$ , $T_J = 175^\circ\text{C}$                                        |
| $Q_C$            | Total Capacitive Charge         | 24          |          | nC            | $V_R = 400\text{ V}$ , $I_F = 10\text{ A}$<br>$di/dt = 500\text{ A}/\mu\text{s}$<br>$T_J = 25^\circ\text{C}$                               |
| C                | Total Capacitance               | 1000<br>91  |          | pF            | $V_R = 0\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$<br>$V_R = 400\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ |
| $E_{\text{ava}}$ | Non-repetitive Avaranche Energy | 220         |          | mJ            | $L=1\text{mH}$                                                                                                                             |

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

| Symbol          | Parameter                                | Typ. | Unit                      |
|-----------------|------------------------------------------|------|---------------------------|
| $R_{\text{JC}}$ | Thermal Resistance from Junction to Case | 0.87 | $^\circ\text{C}/\text{W}$ |

Typical Performance

Fig.1  $V_F - I_F$  Characteristics

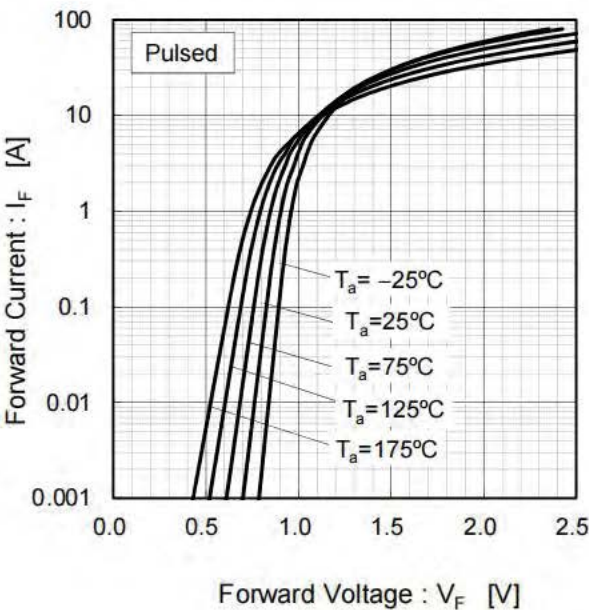
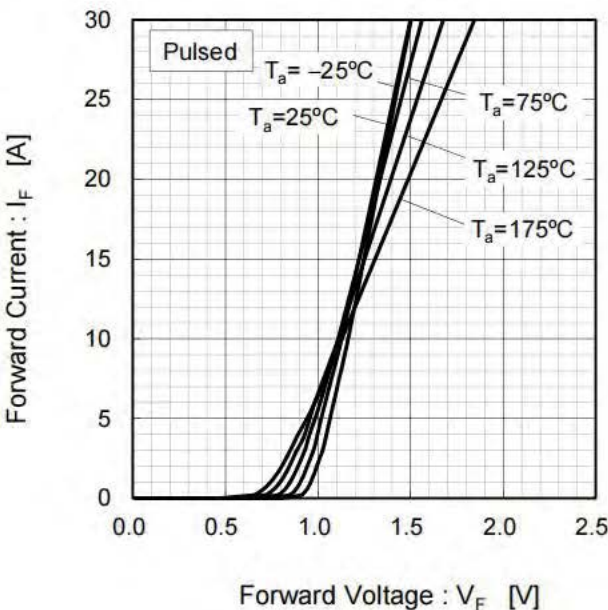


Fig.2  $V_F - I_F$  Characteristics





## Typical Performance

Fig.3  $V_R - I_R$  Characteristics

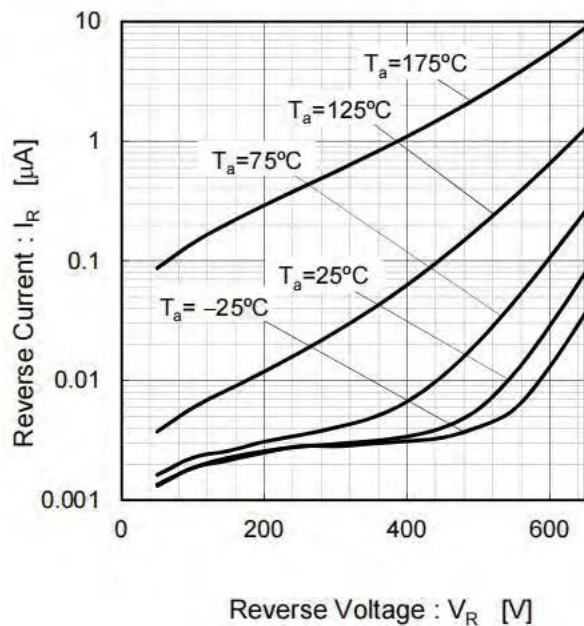


Fig.4  $V_R - C_t$  Characteristics

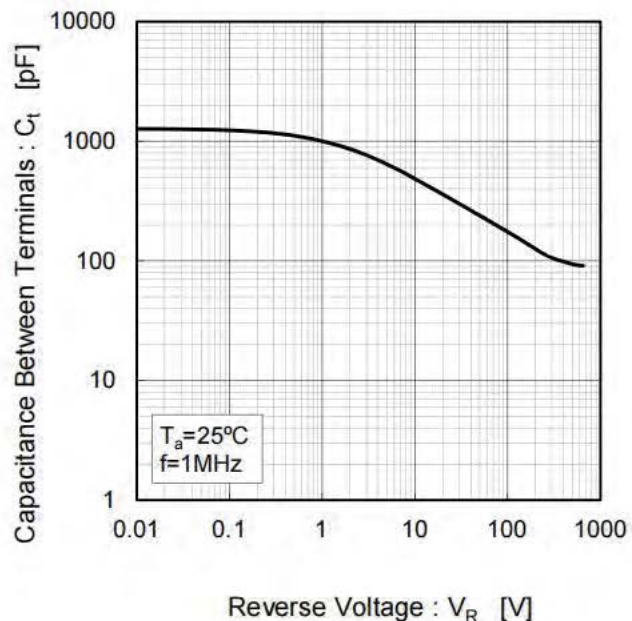


Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

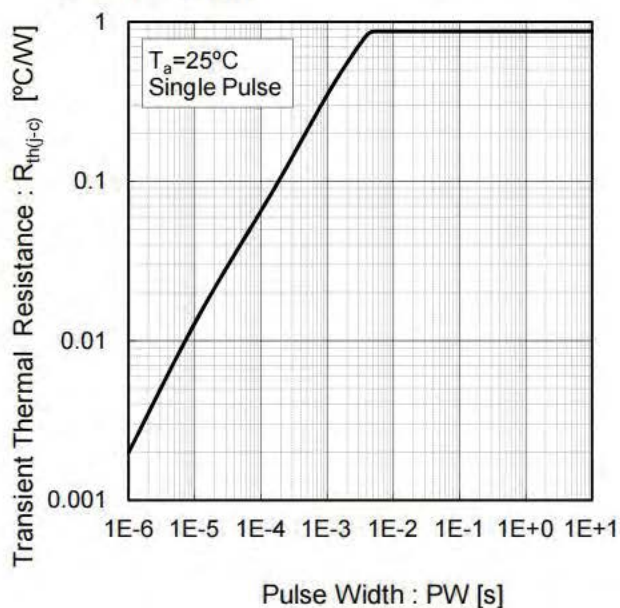
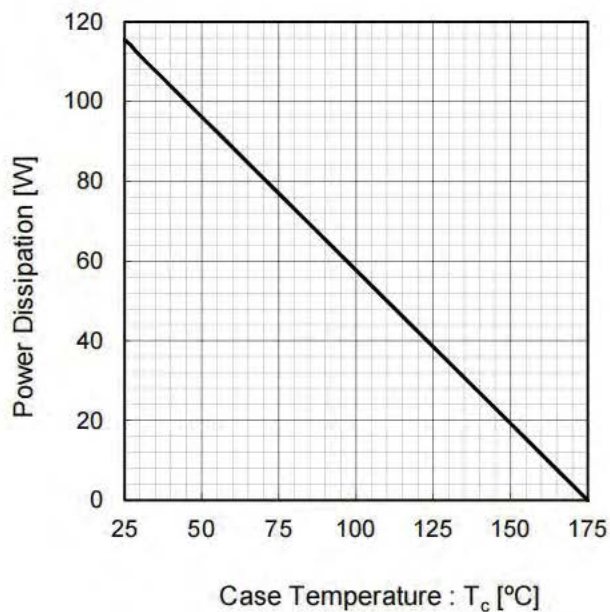


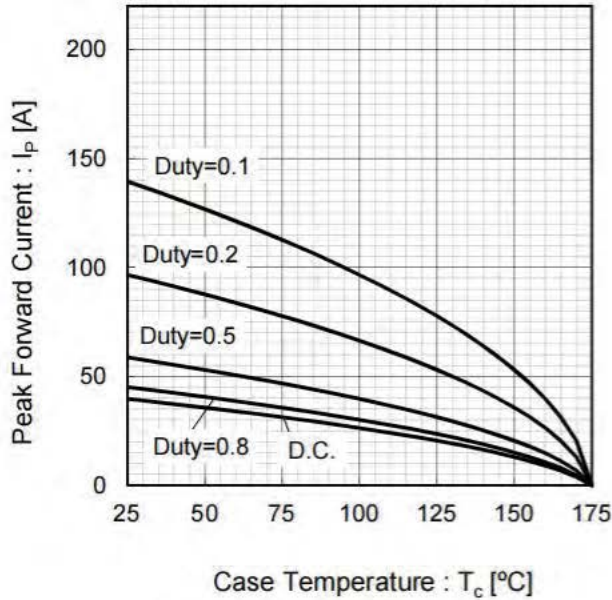
Fig.6 Power Dissipation





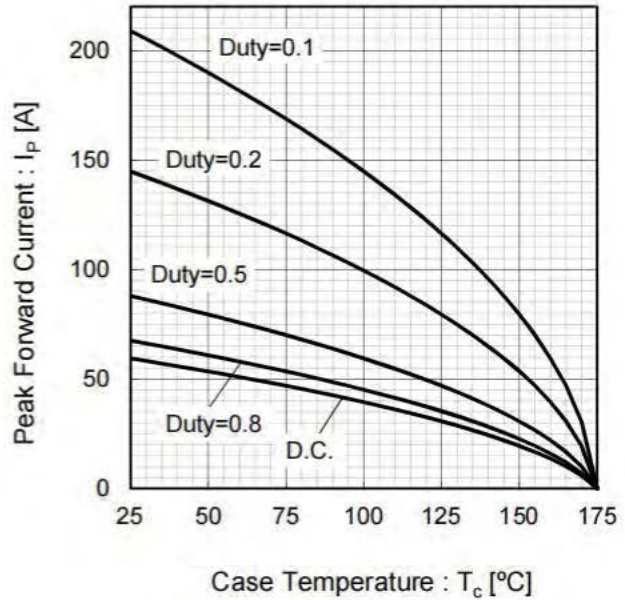
## Typical Performance

Fig.7\*3 Maximum peak forward current derating curve  $I_P - T_c$



\*3 Based on max  $V_f$ , max  $R_{th(j-c)}$   
Valid for switching of above 10kHz,  
excluding D.C. curve.

Fig.8\*4 Typical peak forward current derating curve  $I_P - T_c$  (Not guaranteed)



\*4 Based on typ  $V_f$ , typ  $R_{th(j-c)}$   
Typical value, not guaranteed  
Valid for switching of above 10kHz,  
excluding D.C. curve

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

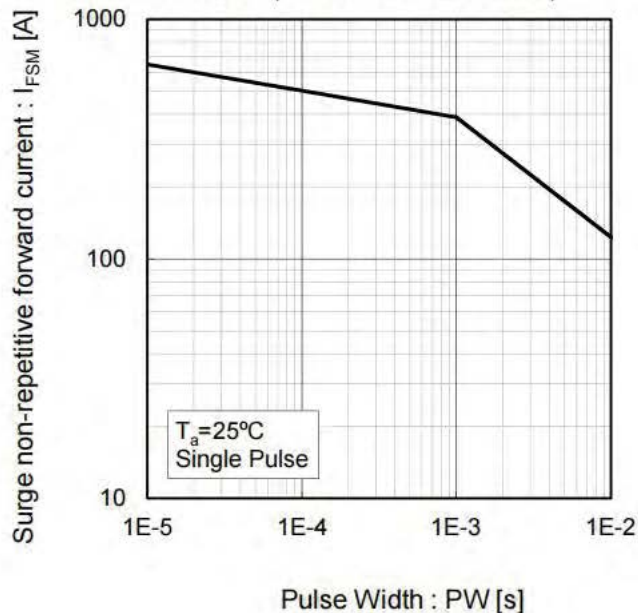
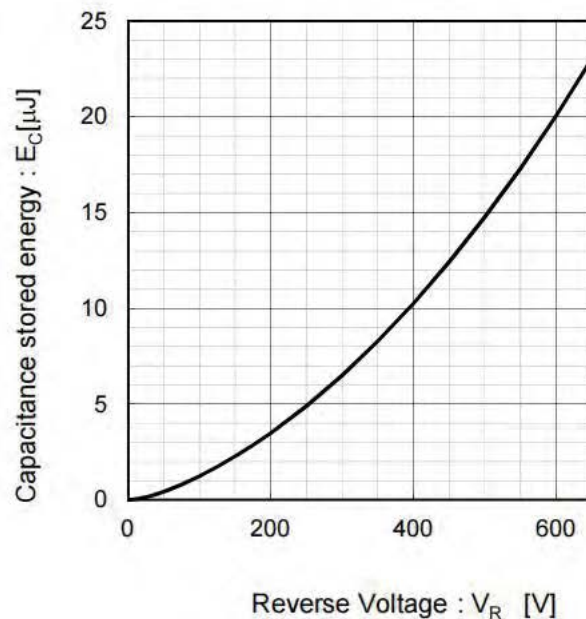


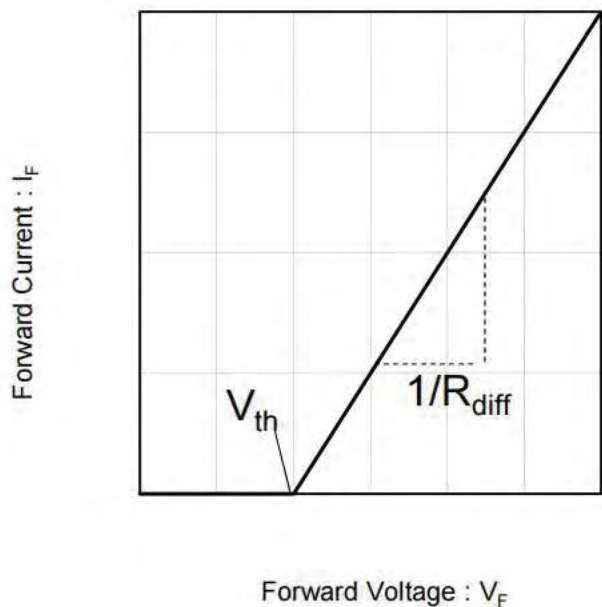
Fig.10 Typical capacitance store energy





Typical Performance

Fig.11 Equivalent forward current curve



$$V_F = V_{th} + R_{diff} I_F$$

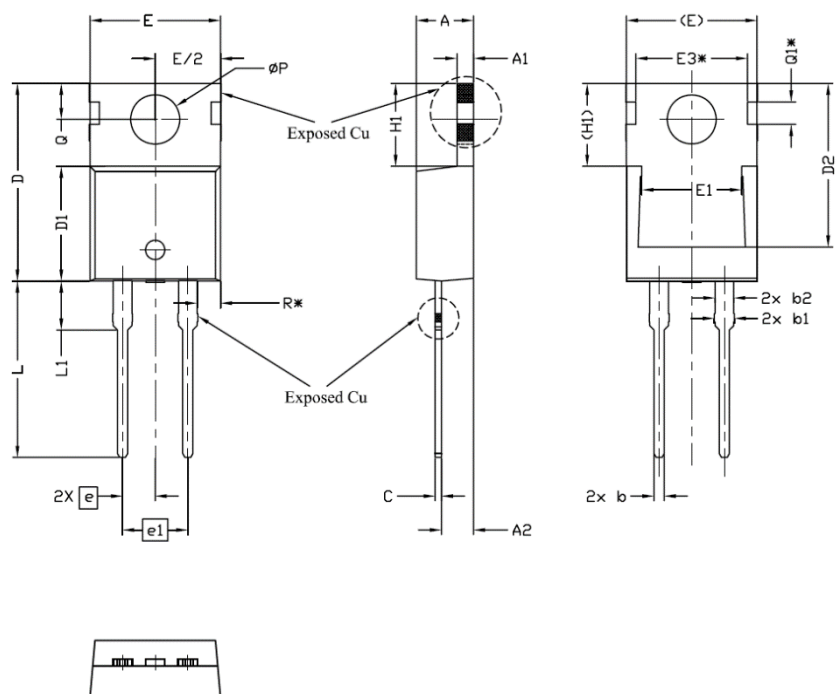
$$V_{th}(T_j) = a_0 + a_1 T_j$$
$$R_{diff}(T_j) = b_0 + b_1 T_j + b_2 T_j^2$$

| Symbol | Typical Value | Unit                      |
|--------|---------------|---------------------------|
| $a_0$  | 9.66E-01      | V                         |
| $a_1$  | - 1.10E-03    | V/°C                      |
| $b_0$  | 1.76E-02      | $\Omega$                  |
| $b_1$  | 3.73E-05      | $\Omega/^\circ\text{C}$   |
| $b_2$  | 3.84E-07      | $\Omega/^\circ\text{C}^2$ |

$T_j$  in °C; -55 °C <  $T_j$  < 175°C ;  $I_F$  < 40A

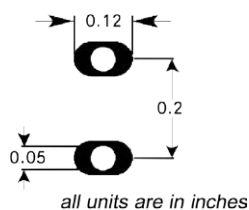


## Package Information TO-220C-2L



| SYMBOL | DIMENSIONS |       |       | NOTES |
|--------|------------|-------|-------|-------|
|        | MIN.       | NOM.  | MAX.  |       |
| A      | 4,24       | 4,44  | 4,64  |       |
| A1     | 1.15       | 1.27  | 1.40  |       |
| A2     | 2.30       | 2,48  | 2,70  |       |
| b      | 0.70       | 0.80  | 0.90  |       |
| b1     | 1.20       | 1,55  | 1,75  |       |
| b2     | 1,20       | 1,45  | 1,70  |       |
| c      | 0.40       | 0.50  | 0.60  |       |
| D      | 14,70      | 15,37 | 16,00 | 4     |
| D1     | 8,82       | 8,92  | 9,02  |       |
| D2     | 12,43      | 12,73 | 12,83 | 5     |
| E      | 9,96       | 10,16 | 10,36 | 4,5   |
| E1     | 6,86       | 7,77  | 8,89  | 5     |
| E3*    | 8,70REF.   |       |       |       |
| e      | 2,54BSC    |       |       |       |
| e1     | 5,08BSC    |       |       |       |
| H1     | 6,30       | 6,45  | 6,60  | 5,6   |
| L      | 13,47      | 13,72 | 13,97 |       |
| L1     | 3,60       | 3,80  | 4,00  |       |
| ØP     | 3,75       | 3,84  | 3,93  |       |
| Q      | 2,60       | 2,80  | 3,00  |       |
| Q1*    | 1,73REF.   |       |       |       |
| R*     | 1,82REF.   |       |       |       |

## Recommended Solder Pad Layout



TO220-2L



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